

Vishay Semiconductors

Low Capacitance Bidirectional ESD Protection Diode in SOT143

Features

- 1-line ESD protection silicon diode
- ESD Immunity ± 30 kV (acc. IEC 61000-4-2)
- Very low capacitance < 2 pF
- Bidirectional, Symmetrical clamping behaviour (BiSy)
- Working Voltage ± 15 V
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC





Pinning-Schematic

3D Bottom View

Marking



20074



GC1 = Type code V 9 = date code year 32 = date code week

Ordering Information

Device Name	Ordering Code	Taped Units per Reel	Reels per Carton Box
GCDA15C-1	GCDA15C-1-GS08	3000 (per 7" reel (8 mm tape))	5

Package Data

Name	Molding Compound Flammability Rating	Soldering Conditions	Weight	Marking Code
SOT143	UL 94 V-0	260 °C/10 s at terminals	8 mg	GC1

Absolute Maximum Ratings

Ratings at 25 °C, ambient temperature unless otherwise specified

Parameter	Test Conditions	Symbol	Value	Unit
Peak Pulse Current	acc. IEC 61000-4-5, 8/20 μs / single shot	I _{PP}	10	А
Peak Pulse Power	acc. IEC 61000-4-5, 8/20 μs / single shot	P _{PP}	300	W
ESD Voltage Immunity	acc. IEC 61000-4-2 / 10 pulses	V _{ESD}	± 30	kV
Operating Temperature	Junction Temperature	Τ _j	- 40 to + 125	°C
Storage Temperature		T _{STG}	- 55 to + 150	°C

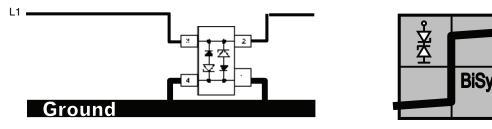
GCDA15C-1

Vishay Semiconductors



BiSy-mode (1-line Bidirectional Symmetrical protection mode)

The **GCDA15C-1** is a 1-line **Bi**directional, **Sy**mmetrical (**BiSy**) protection device. Two avalanche diodes each in series with a PN-Diode providing a very low capacitance. Due to its symmetry the electrical performance is also symmetrical. For an optimal ESD-protection the line inductance of the protection path (current path from the data line (L1) through the protection device to ground) has to be minimized. For this the data line which has to be protected should be led trough the **GCDA15C-1** - one pin (e.g. Pin 3) "in" and the other pin (e.g. Pin 2) "out". The Ground pins (e.g.Pin 1 and 4) should be connected to ground on the shortest and broadest way to keep the inductance as low as possible!



20073

Electrical Characteristics

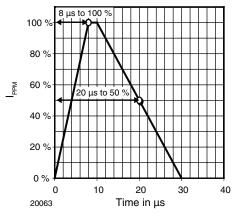
BiSy mode (between Pin 2 + 3 and 1 + 4)

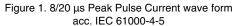
Ratings at 25 °C, ambient temperature unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Тур.	Max	Unit
Reverse Working Voltage	at I _R = 0.1 μA	V _{RWM}	15	16.5		V
Reverse Current	at $V_{R} = V_{RWM} = 15 V$	I _R		< 0.001	0.1	μΑ
Reverse Clamping Voltage	at I _{PP} = 1 A	V _C		18.5	21	V
Reverse Clamping Voltage	at I _{PP} = I _{PPM} = 10 A	V _C		26	30	V
Reverse Break down Voltage	at I _R = 1 mA	V _R	16	17		V
Capacitance	at $V_R = 0 V$, f = 1 MHz	CD		1.5	2	pF
Capacitance	at V _R = 15 V, f = 1 MHz	CD		1.3		pF
ESD-Clamping voltage peak	at ± 8 kV ESD-pulse acc. IEC 61000-4-2	V _{CESD}		130		V
Protection paths	number of lines which can be protected	N _{lines}		1		lines

Typical Characteristics

Ratings at 25 °C, ambient temperature unless otherwise specified





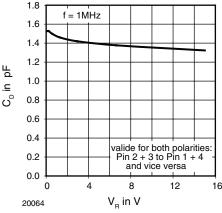


Figure 2. Typical Capacitance C_D vs. Reverse Voltage V_R

www.vishay.com

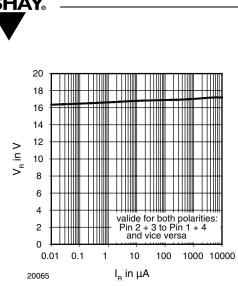


Figure 3. Typical Reverse Voltage V_R vs. Reverse Current I_R

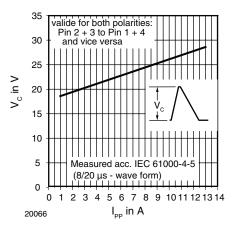


Figure 4. Typical peak clamping voltage V_C vs. peak pulse current $I_{\mbox{PP}}$

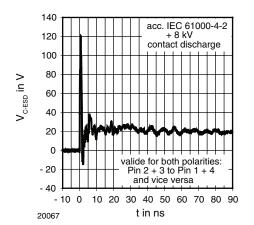
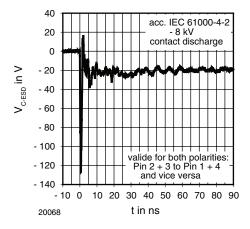


Figure 5. Typical Clamping performance at 8 kV contact discharge (acc. IEC 61000-4-2)



GCDA15C-1

Vishay Semiconductors

Figure 6. Typical Clamping performance at 8 kV contact discharge (acc. IEC 61000-4-2)

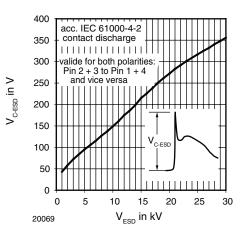


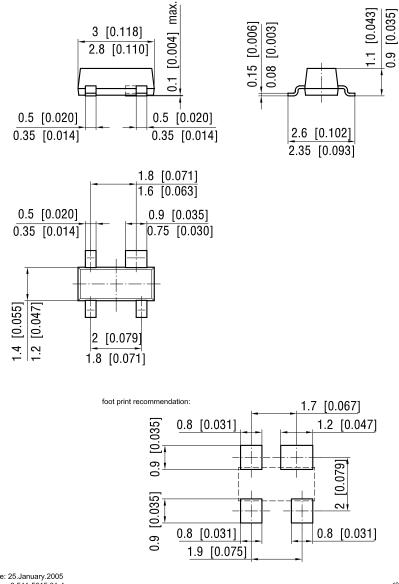
Figure 7. Typical peak clamping voltage at ESD contact discharge (acc. IEC 61000-4-2)

Downloaded from Arrow.com.



Vishay Semiconductors

Package Dimensions in mm (Inches) SOT143



Rev. 5 - Date: 25.January.2005 Document no.: 6.541-5015.01-4

19730



Vishay Semiconductors

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Vishay

Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.